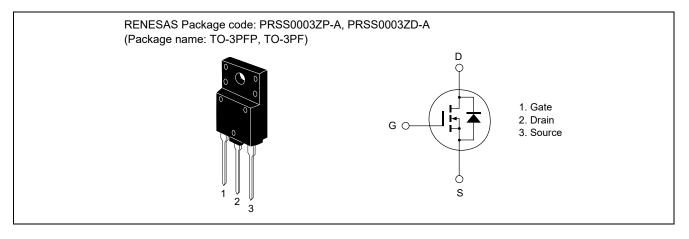


1500V - 2A - MOS FET High Speed Power Switching R07DS1275EJ0300 Rev.3.00 Dec.13.2021

Features

- High breakdown voltage (V_{DSS} = 1500 V)
- High speed switching
- Low drive current
- Quality grade: Standard

Outline



Absolute Maximum Ratings

(Ta = 25 °C) Item Symbol Value Unit 1500 V Drain to source voltage VDSS V Gate to source voltage V_{GSS} ±20 Drain current ΙD 2 А ID(pulse) Notes1 Drain peak current 7 А Body to drain diode reverse drain current 2 А IDR Pch Notes2 Channel dissipation W 50 °C Channel temperature Tch 150 Storage temperature Tstg -55 to +150 °C

Note: Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect a reliability even if it is within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook (Recommendation for Handling and Usage of Semiconductor Devices) and individual reliability data.

2. Value at Tc = 25 °C



Notes: 1. $PW \leq$ 10 $\mu s,\,duty\,cycle \leq$ 1 %

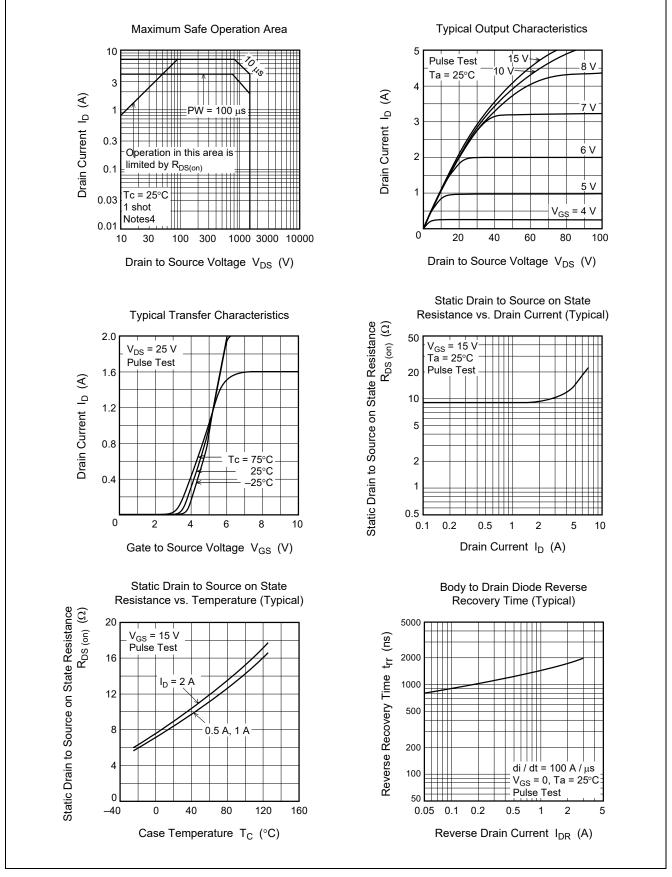
Electrical Characteristics

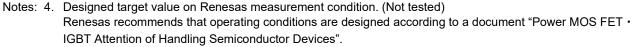
						(Ta = 25 °C)
Item	Symbol	Min	Тур	Мах	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	1500	—	_	V	I _D = 10 mA, V _{GS} = 0
Gate to source leak current	lgss		_	±1	μΑ	V _{GS} = ±20 V, V _{DS} = 0
Zero gate voltage drain current	I _{DSS}		—	500	μΑ	V _{DS} =1200 V, V _{GS} = 0
Gate to source cutoff voltage	V _{GS(off)}	2.0	_	4.0	V	I _D = 1 mA, V _{DS} = 10 V
Static drain to source on state resistance	R _{DS(on)}	_	9	12	Ω	I_D = 1 A, V_{GS} = 15 V ^{Notes3}
Forward transfer admittance	y _{fs}	0.45	0.75		S	I _D = 1 A, V _{DS} = 20 V ^{Notes3}
Input capacitance	Ciss		990	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance	Coss		125	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss		60	_	pF	
Turn-on delay time	t _{d(on)}	_	17	_	ns	I _D = 1 A, V _{GS} = 10 V, R _L = 30 Ω
Rise time	tr	_	50	_	ns	
Turn-off delay time	t _{d(off)}	_	150	_	ns	
Fall time	t _f	_	50	_	ns	
Body-drain diode forward voltage	VDF	_	0.9		V	I _F = 2 A, V _{GS} = 0
Body-drain diode reverse recovery time	t _{rr}		1750	—	ns	I _F = 2 A, V _{GS} = 0, di _F / dt = 100 A / μs

Notes: 3. Pulse Test

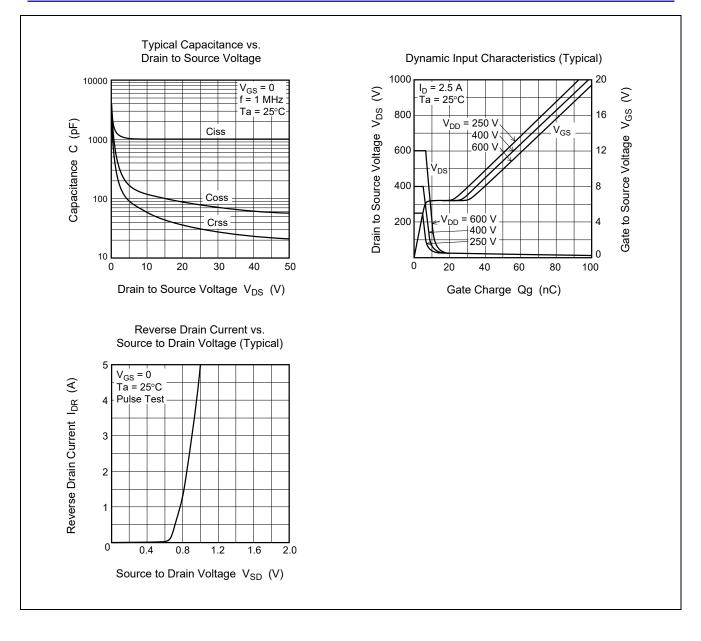


Main Characteristics

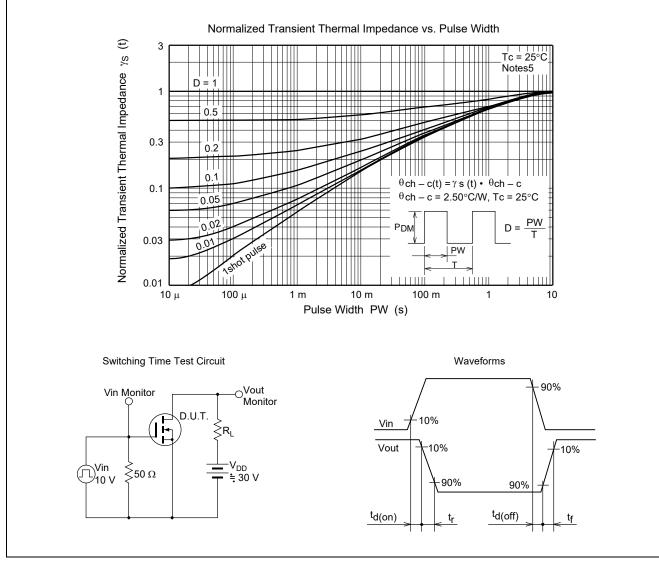










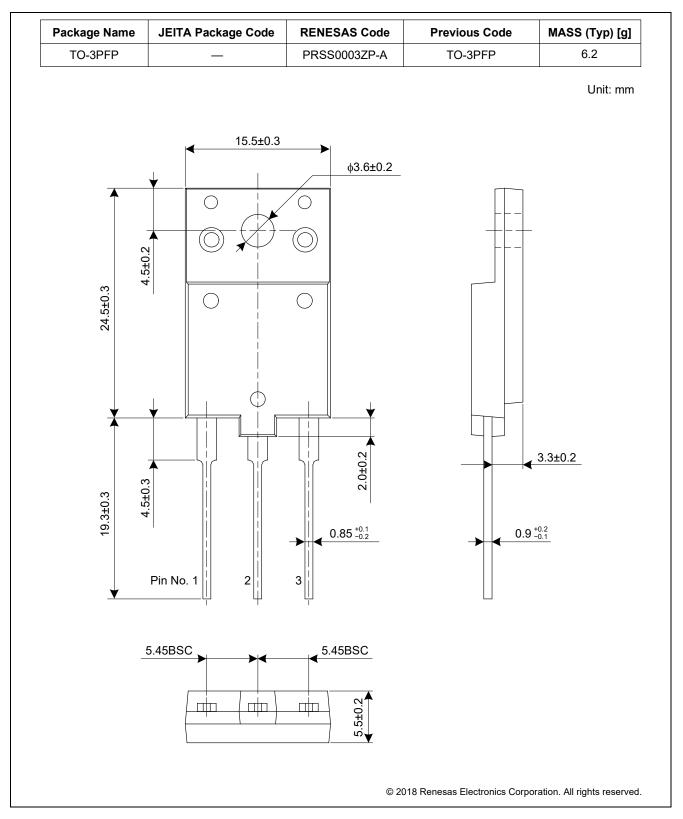


Notes: 5. Designed target value on Renesas measurement condition. (Not tested)



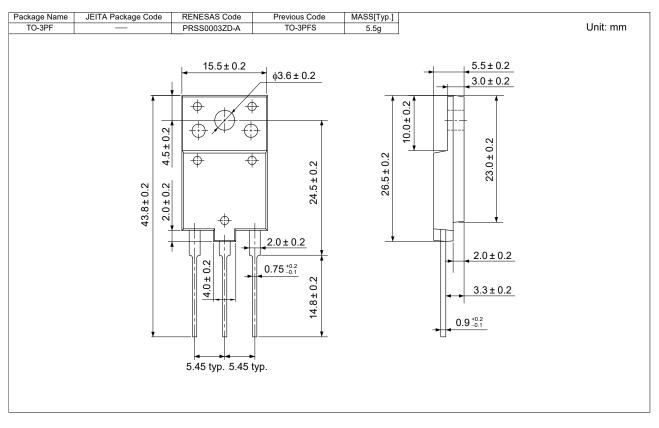
Package Dimensions

ASSEMBLED IN CHINA





ASSEMBLED IN KOREA



Ordering Information

Orderable Part No.	Quantity	Shipping Container
2SK2225-80-E#T2 (ASSEMBLED IN CHINA)	25 pcs	Tube
2SK2225-80-E#T2 (ASSEMBLED IN KOREA)	30 pcs	Tube



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